

TO-252-2L Plastic-Encapsulate MOSFETS

CJU04N60

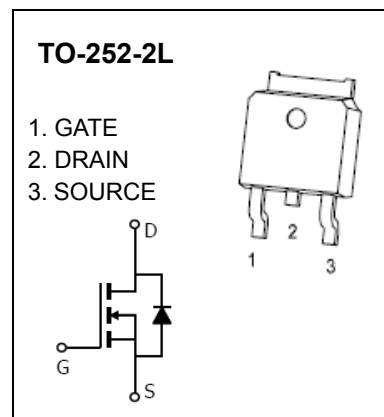
600V N-Channel Power MOSFET

General Description

This advanced high voltage MOSFET is designed to withstand high energy in the avalanche mode and switch efficiently. This new high energy device also offers a drain-to-source diode with fast recovery time. Designed for high voltage, high speed switching applications such as power supplies, converters, power motor controls and bridge circuits.

FEATURE

- High Current Rating
- Lower $R_{ds(on)}$
- Lower Capacitance
- Lower Total Gate Charge
- Tighter VSD Specifications
- Avalanche Energy Specified



Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	600	V
Gate-Source Voltage	V_{GSS}	± 30	
Continuous Drain Current	I_D	4.0	A
Continuous Drain-Source Diode Forward Current	I_S	4.0	
Single Pulsed Avalanche Energy (note1)	E_{AS}	260	mJ
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	100	$^{\circ}\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 ~ +150	$^{\circ}\text{C}$
Maximum lead temperature for soldering purposes , 1/8" from case for 5 seconds	T_L	260	

Electrical characteristics (T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	600			V
Drain-source diode forward voltage(note2)	V _{SD}	V _{GS} = 0V, I _S =4.0A			1.5	
Zero gate voltage drain current	I _{DSS}	V _{DS} =600V, V _{GS} =0V			25	μA
Gate-body leakage current, forward(note2)	I _{GSSF}	V _{DS} =0V, V _{GS} =30V			100	nA
Gate-body leakage current, reverse(note2)	I _{GSSR}	V _{DS} =0V, V _{GS} =-30V			-100	
On characteristics (note2)						
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	2.0		4.0	V
Static drain-source on-resistance	R _{DS(on)}	V _{GS} =10V, I _D =2.0A		2.0	3.0	Ω
Forward transconductance	g _{fs}	V _{DS} =50V, I _D =2A	2.0	2.6		S
Dynamic characteristics (note 3)						
Input capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V,f =1MHz		540	760	pF
Output capacitance	C _{oss}			125	180	
Reverse transfer capacitance	C _{rss}			8.0	20	
Switching characteristics						
Total gate charge	Q _g	V _{DS} =480V,V _{GS} =10V,I _D =4.0A		5.0	10	nC
Gate-source charge	Q _{gs}			2.7		
Gate-drain charge	Q _{gd}			2.0		
Turn-on delay time (note3)	t _{d(on)}	V _{DD} =300V, V _{GS} =10V, R _G =9.1Ω, I _D =4.0A		12	20	ns
Turn-on rise time (note3)	t _r			7.0	10	
Turn-off delay time (note3)	t _{d(off)}			19	40	
Turn-off fall time (note3)	t _f			10	20	

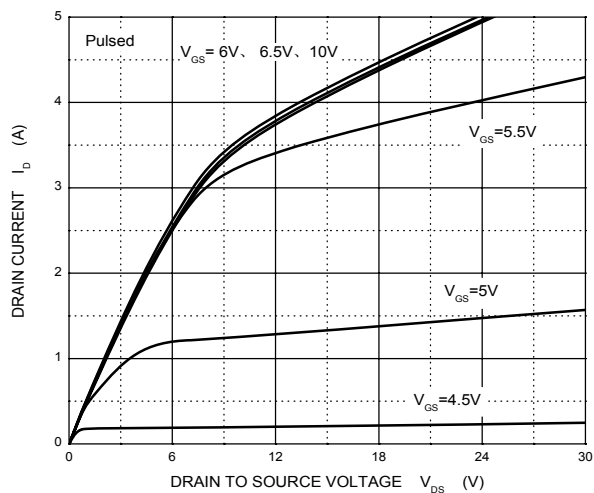
Notes :

1. L=30mH, I_L=4 A, V_{DD}=100V, V_{GS}=10V, R_G=25Ω, Starting T_J=25°C.
2. Pulse Test : Pulse width≤300μs, duty cycle ≤2%.
3. These parameters have no way to verify.

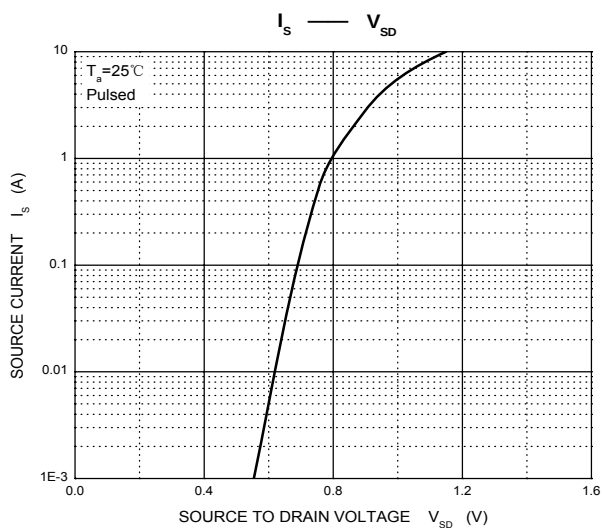
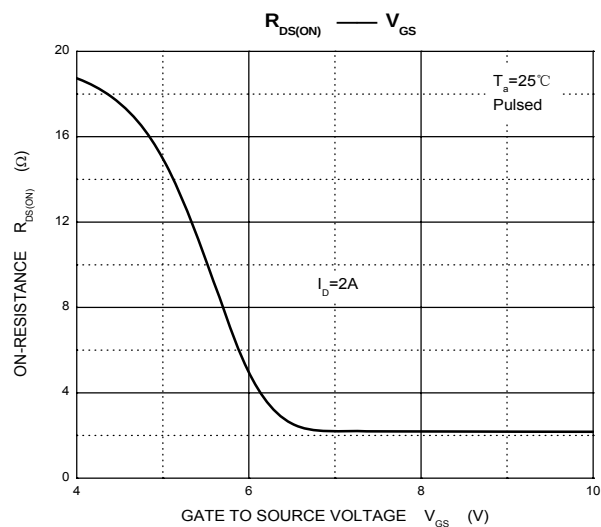
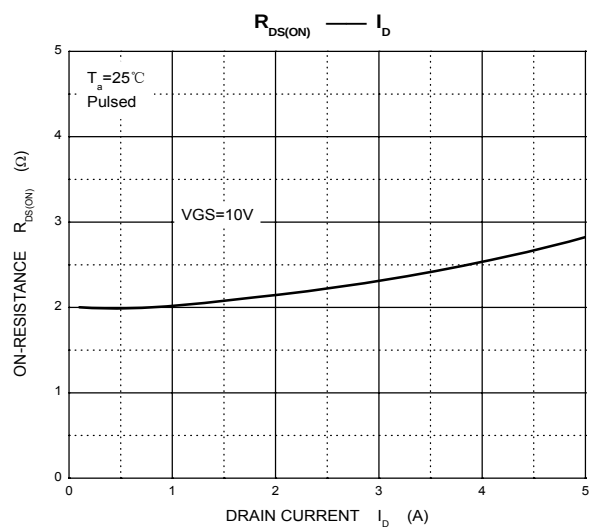
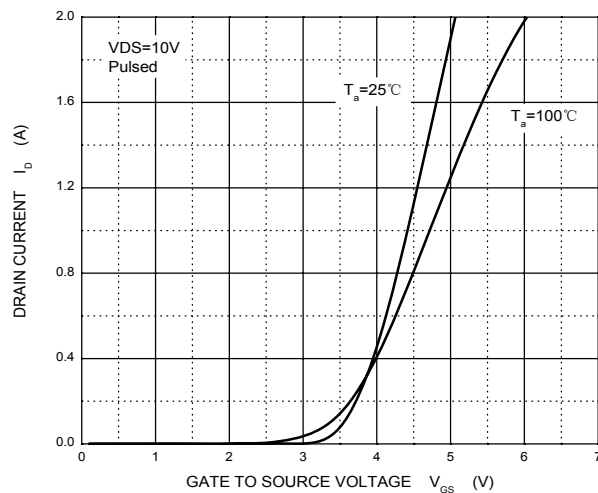
Typical Characteristics

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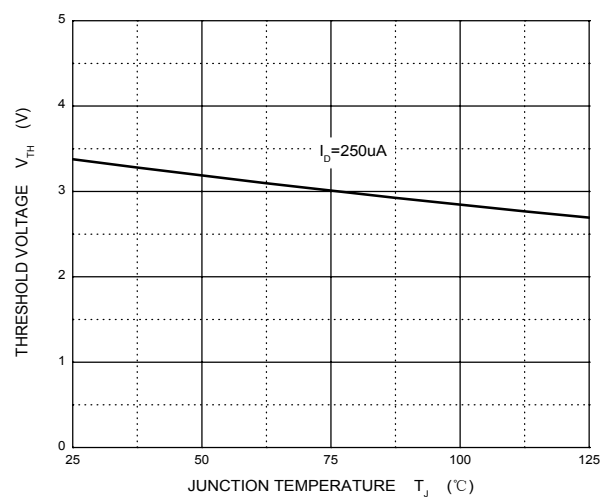
Output Characteristics



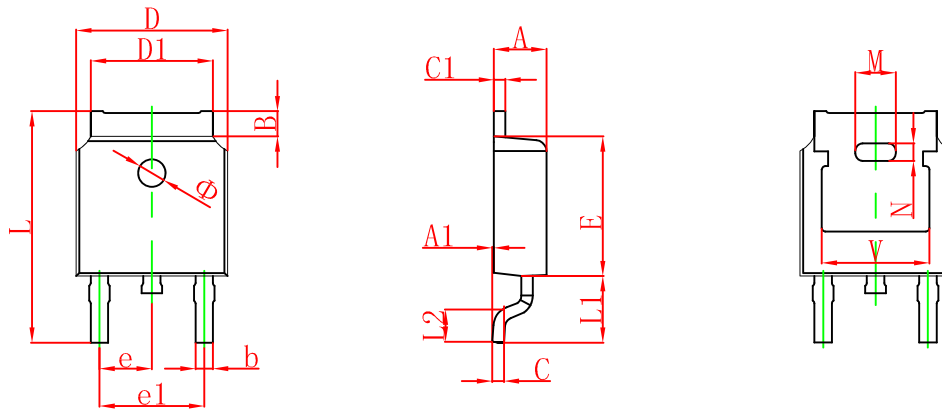
Transfer Characteristics



Threshold Voltage

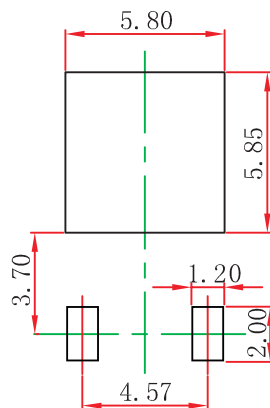


TO-252(4R)-2L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
B	0.800	1.400	0.031	0.055
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
c1	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
E	6.000	6.200	0.236	0.244
e	2.286 TYP.		0.090 TYP.	
e1	4.327	4.727	0.170	0.186
M	1.778 REF.		0.070 REF.	
N	0.762 REF.		0.018 REF.	
L	9.800	10.400	0.386	0.409
L1	2.9 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
V	4.830 REF.		0.190 REF.	
Φ	1.100	1.300	0.043	0.051

TO-252(4R)-2L Suggested Pad Layout



Note:

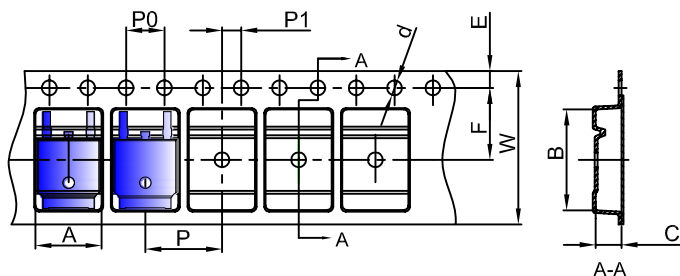
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

TO-252 Tape and reel

TO-252 Embossed Carrier Tape

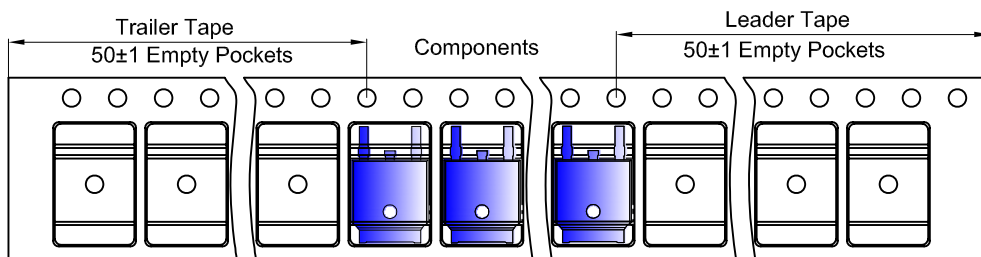


Packaging Description:

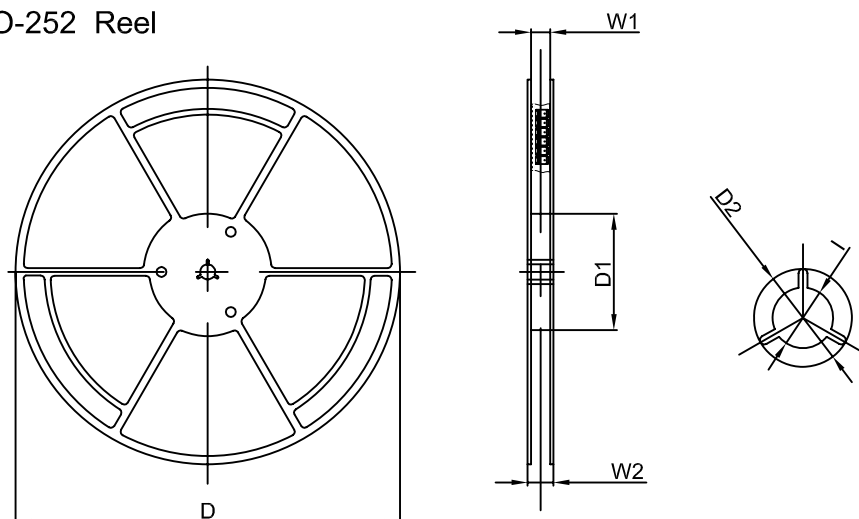
TO-252 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 25,00 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
TO-252	6.90	10.50	2.70	Ø1.55	1.75	7.50	4.00	8.00	2.00	16.00
(Tolerance)	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+/-0.1	+0.3/-0.1

TO-252 Tape Leader and Trailer



TO-252 Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	W1	W2	I
13"Dia	330.00	100.00	Ø21.00	16.40	21.00	Ø13.00
Tolerance	+/-2	+/-1	+/-1	+/-1	+/-1	+/-1

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
2,500 pcs	13inch	2,500 pcs	340×336×29	25,000 pcs	353×346×365	14.04